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0-119-1-3
月 v. E93-C
n. 10
刊

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■ Special Section on Frontier of Thin-Film Transistor Technology

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- 1489 FOREWORD Tanemasa ASANO

PAPERS

- 1490 Polymorphous Silicon: A Promising Material for Thin-Film Transistors for Low-Cost and High-Performance Active-Matrix QLED Displays (INVITED)
..... François TEMPLIER, Julien BROCHET, Bernard AVENTURIER, David COOPER, Alexey ABRAMOV, Dmitri DAINENKA, and Pere ROCA i CABARROCAS
- 1495 Rapid-Thermal Annealing of Amorphous Silicon on Oxide Semiconductors Saurabh SAXENA and Jin JANG
- 1499 Opto-Thermal Analysis of Blue Multi Laser Diode Annealing (BLDA)
..... Katsuya SHIRAI, Takashi NOGUCHI, Yoshiaki OGINO, and Eiji SAHOTA
- 1504 Oxide Thin Film Transistor Circuits for Transparent RFID Applications (INVITED)
..... Seung Hyun CHO, Sang Woo KIM, Woo Seok CHEONG, Chun Won BYUN, Chi-Sun HWANG, Kyoung Ik CHO, and Byung Seong BAE
- 1511 Electrical Properties of $Ba_{0.5}Sr_{0.5}Ta_2O_6$ Thin Film Fabricated by Sol-Gel Method
..... Li LU, Masahiro ECHIZEN, Takashi NISHIDA, Kiyoshi UCHIYAMA, and Yukiharu URAOKA

BRIEF PAPER

- 1516 Properties of SiO_2 Surface and Pentacene OTFT Subjected to Atomic Hydrogen Annealing
..... Akira HEYA and Naoto MATSUO

Regular Section

PAPERS

- Electronic Circuits
1518 LDO Design Methodology and an Intelligent Power Management Sub-System IC for CDMA Handsets
..... Tsutomu WAKIMOTO
- Integrated Electronics
1525 Performance and Power Modeling of On-Chip Bus System for a Complex SoC
..... Hyun LEE, Je-Hoon LEE, and Kyoung-Rok CHO

(continued on back cover)



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VOL.E93-C NO.10
OCTOBER 2010

BRIEF PAPERS**Microwaves, Millimeter-Waves**

- 1536 A 0.13- μm CMOS Ultra-Wideband Low-Noise Amplifier with High Impedance n -Well Terminals
Chang-Wan KIM and Bong-Soo KANG

Electronic Circuits

- 1540 Heuristic Sizing Methodology for Designing High-Performance CMOS Level Converters with Balanced Rise and Fall Delays
Jinn-Shyan WANG, Yu-Juey CHANG, and Chingwei YEH

Electronic Components

- 1544 Architecture and Analysis of Sub-Nyquist Rate Sampling for Behavioral Modeling of Wideband Power Amplifiers
Youngcheol PARK and Hyunchul KU

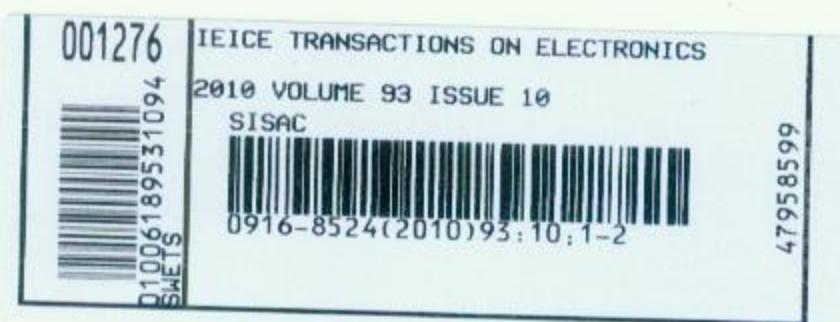
LETTERS**Microwaves, Millimeter-Waves**

- 1548 Modeling of Non-linearity in Digitally Controlled Oscillator in 0.18 μm CMOS Technology
Abhishek TOMAR, Shashank LINGALA, Ramesh K. POKHAREL, Haruichi KANAYA, and Keiji YOSHIDA

Semiconductor Materials and Devices

- 1550 Equivalent Noise Temperature Representation for Scaled MOSFETs
Hiroshi SHIMOMURA, Kuniyuki KAKUSHIMA, and Hiroshi IWAI

1553 ABSTRACTS (IEICE Trans. Electron. (Japanese Edition), Vol. J93-C, No. 10)



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